Pin diode RN741V

Applications

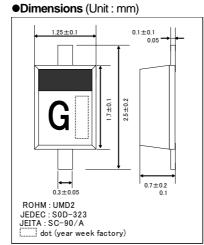
Attenuator

● Features

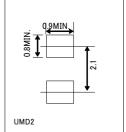
- 1) Small mold type. (UMD2)
- 2) Low capacitance

Construction

Silicon epitaxial planar



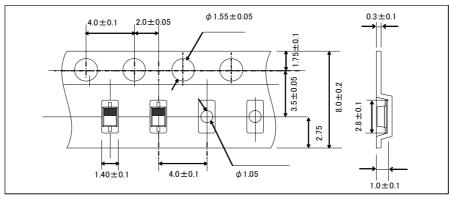
●Land size figure



Structure



●Taping dimensions (Unit:mm)



● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Reverse voltage	V_R	50	V
Forward current	I _F	50	mA
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

●Electrical characteristic (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	V_{F}	-	1	1	V	I _F =10mA
Reverse current	I _R	-	-	0.1	μA	V _R =50V
Capacitance between current	Ct	-	-	0.4	pF	V _R =35V , f=1MHz
High frequency resistance	Rf	-	-	10	Ω	I _F =10mA,f=100MHz

•Electrical characteristic curves 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1000 | 1 f=1MHz FORWARD CURRENT:IF(mA) CAPACITANCE BETWEEN TERMINALS:Ct(pF) #1# Ta=125°C 10 15 20 25 REVERSE VOLTAGE:VR(V) FORWARD VOLTAGE: VF(mV) REVERSE VOLTAGE: VR(V) VF-IF CHARACTERISTICS VR-IR CHARACTERISTICS VR-Ct CHARACTERISTICS Ta=25°C Ta=25°C 1000 FORWARD OPERATING RESISTANCE:rf(\Omega) CAPACITANCE BETWEEN TERMINA LS:Ct(pF) 100 =100MHz FORWARD AVE:851.1mV 0.1 10 FREQUENCY(MHz) FORWARD CURRENT:IF(mA) VF DISPERSION MAP rf-IF CHARACTERISTICS Ct-f CHARACTERISTICS Ta=25°C Ta=25°C VR=50V f=100MHz VR=1V IF=10mA REVERSE CURRENTIR(nA) n=10pcs 0.2 1186.5... FORWARD CURRENT:IF(mA) IR DISPERSION MAP Ct DISPERSION MAP rf DISPERSION MAP Ta=25°C f=100MHz IF=10mA DDISCHARGE TEST ESD(KV) FORWARD OPERATING RESISTANCE:rf(立) n=10pcs AVE:3.406 Ω FORWARD CURRENT:IF(mA) ESD DISPERSION MAP rf DISPERSION MAP



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